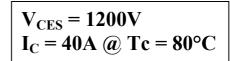
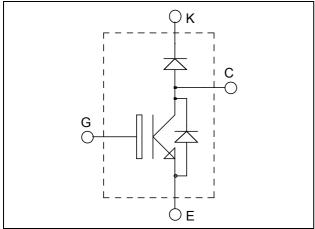


ISOTOP® Boost chopper Trench + Field Stop IGBT4 Power module





Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction
- Brake switch

Features

- Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- ISOTOP® Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

- Low conduction losses
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
ī	Continuous Collector Current	$T_C = 25^{\circ}C$	65	
I_{C}		$T_C = 80$ °C	40	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	70	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25^{\circ}C$	220	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	70A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.85	2.25	V
$V_{CE(sat)}$		$I_C = 35A$ $T_j = 150^{\circ}C$		2.25		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1.2 \text{mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			1950		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			155		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			115		
Q_{G}	Gate charge	$V_{GE} = \pm 15V$; $V_{CE} = 600V$ $I_{C} = 35A$			0.27		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switc	hing (25°C)		130		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			20		
$T_{d(off)}$	Turn-off Delay Time	$V_{CE} = 600V$ $I_{C} = 35A$			300		
$T_{\rm f}$	Fall Time	$R_G = 12\Omega$			45		İ
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_{C} = 35A$ $R_{G} = 12\Omega$			150		ns
$T_{\rm r}$	Rise Time				35		
$T_{d(off)}$	Turn-off Delay Time				350		
T_{f}	Fall Time				80		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$	$T_J = 25^{\circ}C$		2.6		mJ
Lon	Turn-on Switching Energy	$V_{CE} = 600V$	$T_{J} = 150^{\circ}C$		4		1113
E_{off}	Turn-off Switching Energy	$I_C = 35A$	$T_J = 25$ °C		2		mJ
Loff	Turn-on Switching Energy	$R_G = 12\Omega$	$T_{\rm J} = 150^{\circ}{\rm C}$		3		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bu}$ $t_p \le 10 \mu s ; T_j = 1$			140		A

Chopper diode ratings and characteristics

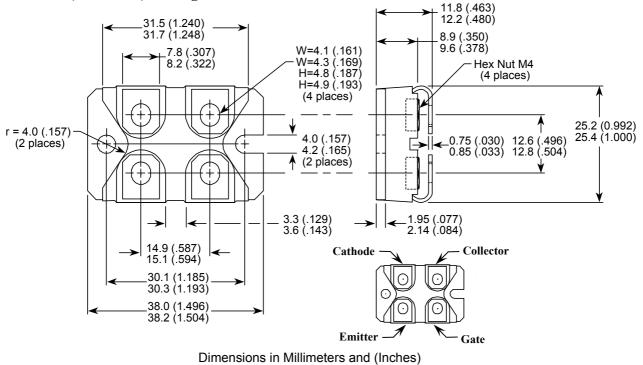
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$			100	۸
1 _{RM}	Waximum Reverse Leakage Current	V _R -1200 V	$T_{\rm j} = 150^{\circ}{\rm C}$			500	μΑ
I_F	DC Forward Current		$Tc = 80^{\circ}C$		30		Α
	Diode Forward Voltage	$I_F = 30A$			2.6	3.1	
$V_{\rm F}$		$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.8		
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C		300		ns
	Reverse Recovery Time	$I_F = 30A$ $V_R = 800V$	$T_{j} = 125^{\circ}C$		380		113
Q _{rr}	Reverse Recovery Charge	$di/dt = 200 \text{ A/}\mu\text{s}$	$T_j = 25$ °C		360		nC
	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		1700		IIC



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT			0.68	°C/W
		Diode			1.2	
R_{thJA}	Junction to Ambient (IGBT & Diode)				20	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V
T_{J}, T_{STG}	Storage Temperature Range		-55		175	°C
$T_{ m L}$	Max Lead Temp for Soldering:0.063" from case for 10 sec				300	C
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m
Wt	Package Weight			29.2		g

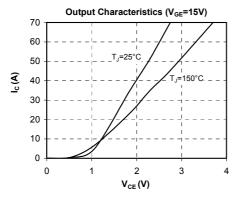
SOT-227 (ISOTOP®) Package Outline

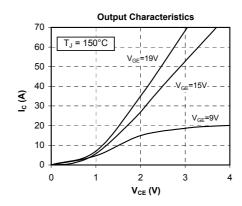


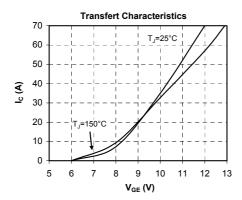
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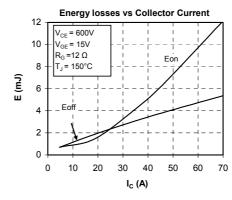


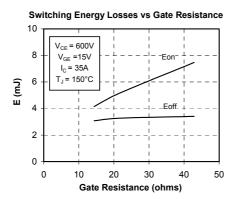
Typical Performance Curve

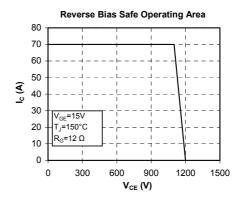


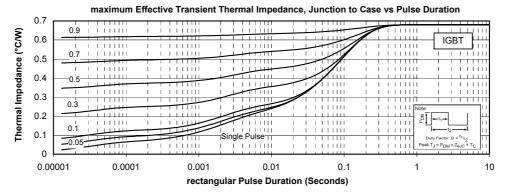






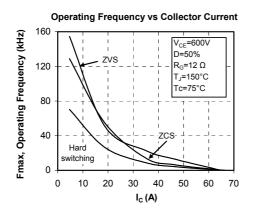


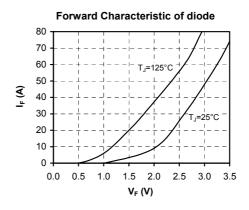




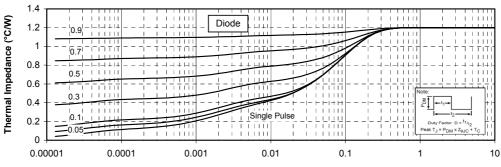
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rectangular Pulse Duration (Seconds)



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